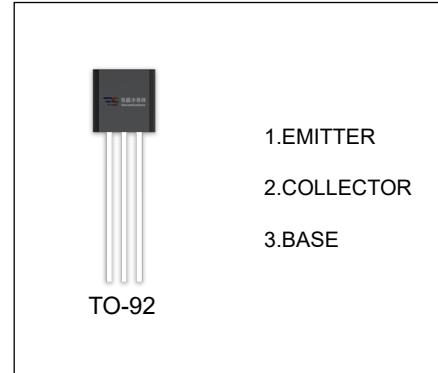


2SC1213A TRANSISTOR (NPN)

FEATURES

- Low Frequency Amplifier
- Complementary Pair with 2SA673A



ORDERING INFORMATION

Part Number	Package	Packing Method	Pack Quantity
2SC1213A	TO-92	Bulk	1000pcs/Bag
2SC1213A-TA	TO-92	Tape	2000pcs/Box

MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	50	V
V_{CEO}	Collector-Emitter Voltage	50	V
V_{EBO}	Emitter-Base Voltage	4	V
I_C	Collector Current	0.5	A
P_c	Collector Power Dissipation	400	mW
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	312	°C/W
T_J, T_{stg}	Operation Junction and Storage Temperature Range	-55~+150	°C

$T_a=25^\circ C$ unless otherwise specified

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=0.01mA, I_E=0$	50			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=1mA, I_B=0$	50			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=0.01mA, I_C=0$	4			V
Collector cut-off current	I_{CBO}	$V_{CB}=20V, I_E=0$			0.5	μA
Emitter cut-off current	I_{EBO}	$V_{EB}=3V, I_C=0$			0.1	μA
DC current gain	$h_{FE(1)}$	$V_{CE}=3V, I_C=10mA$	60		320	
	$h_{FE(2)}$	$V_{CE}=3V, I_C=500mA$	10			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=150mA, I_B=15mA$			0.6	V
Base-emitter voltage	V_{BE}	$V_{CE}=3V, I_C=10mA$			0.75	V

CLASSIFICATION OF $h_{FE(1)}$

RANK	B	C	D
RANGE	60-120	100-200	160-320